

SURFACE MOUNT GLASS PASSIVATED HIGH EFFICIENCY SILICON RECTIFIER

HFM101 THRU HFM108

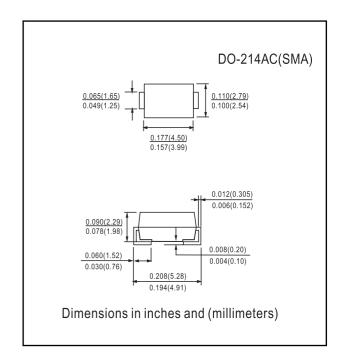
50V-1000V 1.0A

FEATURES

- * Glass passivated device
- * Ideal for surface mounted applications
- * Low leakage current
- * Metallurgically bonded construction
- * Mounting position: Any
- * Weight: 0.057 gram

Mechanical Data

* Epoxy: Device has UL flammability classification 94V-0



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	HFM101	HFM102	HFM103	HFM104	HFM105	HFM106	HFM107	HFM108	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	300	400	600	800	1000	Volts
Maximum RMS Volts	VRMS	35	70	140	210	280	420	560	700	Volts
Maximum DC Blocking Voltage	Voc	50	100	200	300	400	600	800	1000	Volts
Maximum Average Forward Current at TA = 50° C	lo	1.0								Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	IFSM	30								Amps
Typical Junction Capacitance (Note 2)	Cu	15						12		
Pulse energy, non repetitive(inductive load switch off)	ER	20							mJ	
Operating and Storage Temperature Range	TJ, TSTG	-65 to + 150							C	

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS		SYMBOL	HFM101	HFM102	HFM103	HFM104	HFM105	HFM106	HFM107	HFM108	UNITS
Maximum Forward Voltage at 1.0A DC		VF	1.0		1.3		1.7		Volts		
Maximum Full Load Reverse Current, Full cycle Average Ta = 55°C			50					uAmps			
Maximum DC Reverse Current at	@TA = 25°C	l _R	5.0								uAmps
Rated DC Blocking Voltage	@TA = 125°C		100								uAmps
Maximum Reverse Recovery Time (Note 1)		trr	50				75			nSec	

NOTES: 1. Test Conditions: IF=0.5A, IR=-1.0A, IRR=-0.25A.

2. Measured at 1 MHz and applied reverse voltage of 4.0 volts.



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RATINGS AND CHARACTERISTIC CURVES HFM101 THRU HFM108

